# NUR460P

# Ultrafast power diode 27 August 2012

**Product data sheet** 

## 1. Product profile

## 1.1 General description

Ultrafast power diode in a SOD141 (DO-201AD) axial lead plastic package.

#### 1.2 Features and benefits

- Axial leaded plastic package
- Fast switching
- High voltage capability
- Low forward voltage drop
- Low leakage current
- Low thermal resistance
- Soft recovery characteristic

## 1.3 Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- High frequency switched-mode power supplies

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage			-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; square-wave pulse; Fig. 1; Fig. 2		-	-	4	Α
Static characte	Static characteristics					,	
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 3 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>		-	0.82	1.05	V
Dynamic chara	acteristics						
t <sub>rr</sub>	reverse recovery time	$I_F$ = 1 A; $V_R$ = 30 V; $dI_F/dt$ = 50 A/ $\mu$ s; $T_j$ = 25 °C; Ramp Recovery; Fig. 5		-	-	75	ns
		$I_R = 1 \text{ A}; I_F = 0.5 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ Step Recovery}; Fig. 6$		-	-	50	ns





Ultrafast power diode

# 2. Pinning information

### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	k a	K — A
2	Α	anode	DO-201AD (SOD141)	001aaa020

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NUR460P	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L01	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L02	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L03	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L04	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
V <sub>RWM</sub>	crest working reverse voltage		-	600	V
V <sub>R</sub>	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; square-wave pulse; Fig. 1; Fig. 2	-	4	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; square-wave pulse	-	8	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	100	А
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	110	А
T <sub>stg</sub>	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C

## **Ultrafast power diode**

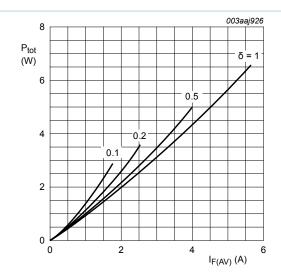


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$
  
 $V_O = 0.947 \text{ V}; \text{ R}_S = 0.037 \Omega$ 

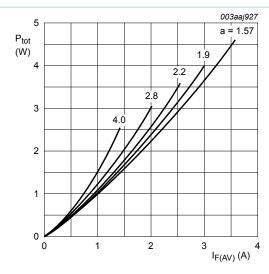
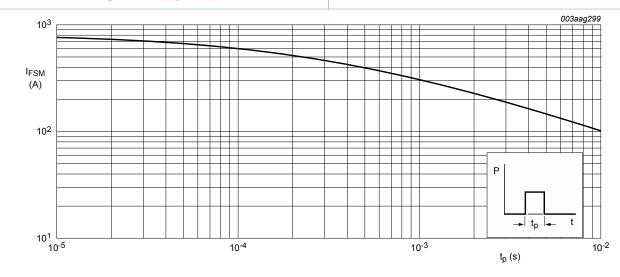


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

a = form factor = 
$$I_{F(RMS)}/I_{F(AV)}$$
  
V<sub>O</sub> = 0.947 V; R<sub>S</sub> = 0.037  $\Omega$ 



## Fig. 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

## 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	55	-	K/W

NUR460P

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## 6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	racteristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 3 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	-	1.25	V
		I <sub>F</sub> = 3 A; T <sub>j</sub> = 150 °C; <u>Fig. 4</u>	-	0.82	1.05	V
		I <sub>F</sub> = 4 A; T <sub>j</sub> = 25 °C; <u>Fig. 4</u>	-	-	1.28	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	10	μΑ
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	250	μΑ
Dynamic c	haracteristics	1				
t <sub>rr</sub>	reverse recovery time	$I_F$ = 1 A; $V_R$ = 30 V; $dI_F/dt$ = 50 A/ $\mu$ s; $T_j$ = 25 °C; Ramp Recovery; Fig. 5	-	-	75	ns
		$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ Step Recovery}; Fig. 6$	-	-	50	ns

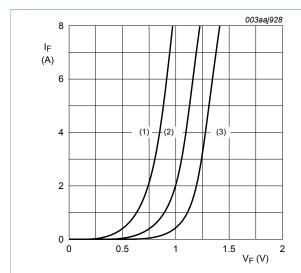


Fig. 4. Forward current as a function of forward voltage

(1)  $T_j = 150$  °C; typical values;

(2)  $T_j = 150$  °C; maximum values;

(3)  $T_j = 25$  °C; maximum values;

 $V_O = 0.947 \text{ V}; R_S = 0.037 \Omega$ 

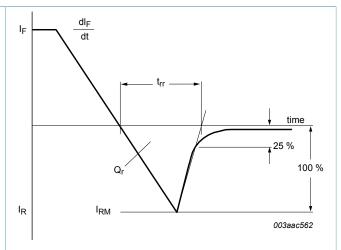
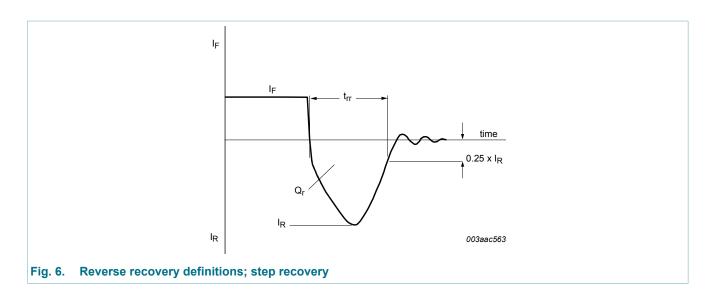
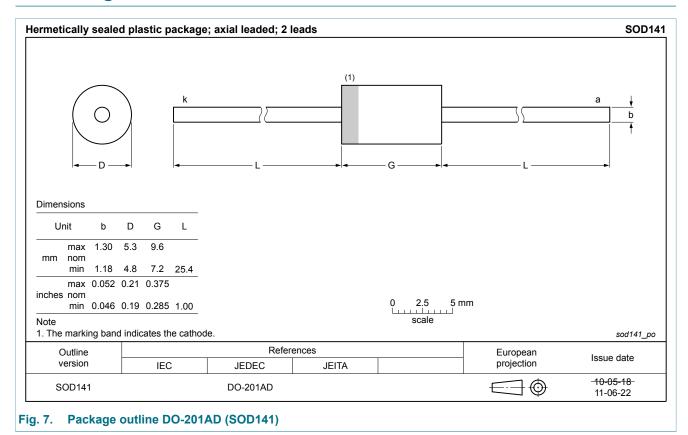


Fig. 5. Reverse recovery definitions; ramp recovery

## **Ultrafast power diode**



## 7. Package outline



**Product data sheet** 

#### Ultrafast power diode

## 8. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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## Ultrafast power diode

## 9. Contents

1	Product profile	1
1.1	General description	
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	3
6	Characteristics	4
7	Package outline	5
8	Legal information	6
8.1	Data sheet status	6
8.2	Definitions	6
8.3	Disclaimers	6
8.4	Trademarks	7

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